## NSN 5961-01-145-8747

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-145-8747 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **End Application:** 4935nc400005h 81205 **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-72 **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 25.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 125.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source **Current Rating Per Characteristic:** 100.00 milliamperes drain current **Power Rating Per Characteristic:** 375.0 milliwatts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No

Fiig:

A110a0